

PRELIMINARY

Notice: This is not a final specification
Some parametric are subject to change.

RT3A77M

Composite Transistor
For General Purpose High Current Drive Application
Silicon PNP Epitaxial Type

DESCRIPTION

RT3A77M is compound transistor built with two 2SA2166 chips in SC-88 package.

FEATURE

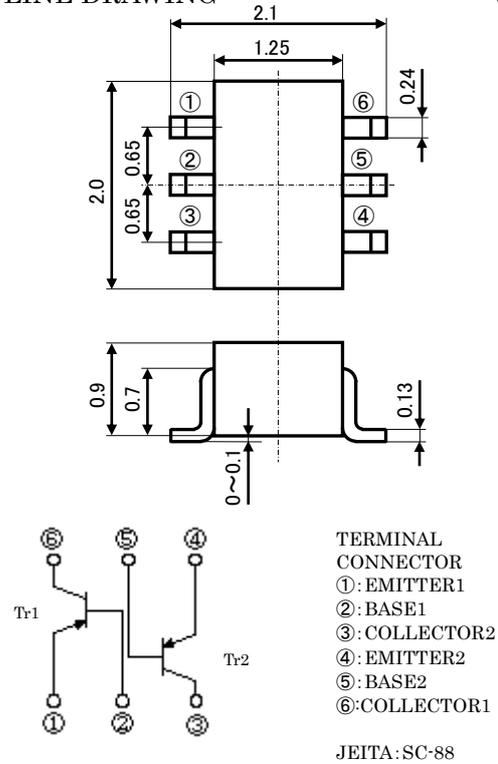
- High collector current
- Low collector to emitter saturation voltage
- Each transistor elements are independent
- Mini package for easy mounting

APPLICATION

For switching application, small type motor drive application

OUTLINE DRAWING

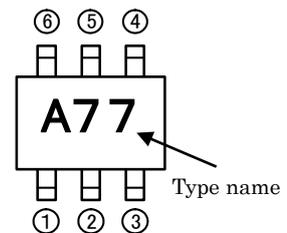
Unit: mm



MAXIMUM RATING (Ta=25°C) (Tr1, Rr2)

SYMBOL	PARAMETER	RATING	UNIT
V _{CEO}	Collector to Emitter voltage	-60	V
V _{CBO}	Collector to Base voltage	-60	V
V _{EBO}	Emitter to Base voltage	-5	V
I _C	Collector current	-500	mA
P _T	Total dissipation	200	mW
T _j	Junction temperature	+150	°C
T _{stg}	Storage temperature	-55~+150	°C

MARKING



ELECTRICAL CHARACTERISTICS (Ta=25°C) (Tr1, Rr2)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V _{(BR)CEO}	Collector to Emitter breakdown voltage	I _C =-1mA, I _B =0	-60	-	-	V
V _{(BR)CBO}	Collector to Base breakdown voltage	I _C =-10μA, I _E =0	-60	-	-	V
V _{(BR)EBO}	Emitter to Base breakdown voltage	I _E =-10μA, I _C =0	-5	-	-	V
I _{CBO}	Collector cut off current	V _{CB} =-50V, I _E =0	-	-	-0.1	μA
I _{EBO}	Emitter cut off current	V _{EB} =-3V, I _C =0	-	-	-0.1	μA
h _{FE}	DC forward current gain	V _{CE} =-10V, I _C =-150mA	100	-	300	-
V _{CE(sat)}	Collector to Emitter saturation voltage	I _C =-150mA, I _B =-15mA	-	-	-0.4	V
V _{BE(sat)}	Base to Emitter saturation voltage	I _C =-150mA, I _B =-15mA	-	-	-1.3	V
f _T	Gain band width product	V _{CE} =-20V, I _E =50mA, f=100MHz	200	-	-	MHz
C _{ob}	Collector output capacitance	V _{CB} =-10V, f=1MHz	-	-	8	pF

Keep safety first in your circuit designs!

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